

DIO2362H

Ultra Low Vos, Low Power Amplifier

Features

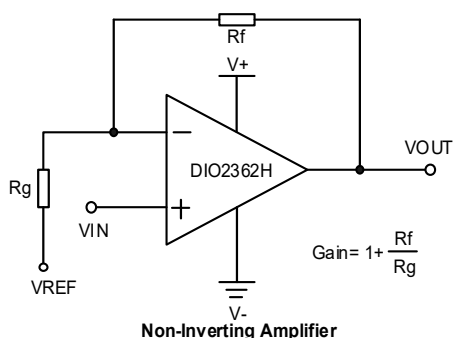
- Ultra low V_{OS} : 35 μ V(Max)
- Low Power: 17.0 μ A(typ.)
- Unity Gain Stable
- Gain Bandwidth Product: 300kHz(typ.)
- Wide supply range: 1.8V to 5.5V
- Available in DFN2*2-8 package
- Temperature Range:
 - Industrial: -40°C to 85°C
 - Extended: -40°C to 125°C

Descriptions

DIO2362H is ultra low V_{OS} operational amplifier, with rail-to-rail CMOS input/output and single/dual channels selectable. DIO2362H has a gain-bandwidth product of 300kHz(typ.), wide operating supply voltage from 1.8V to 5.5V and broad output voltage swing.

DIO2362H consumes ultra low power, with each channel 17.0 μ A(typ.) of bias current, which makes DIO2362H be ideal for battery powered device, temperature-sense device, etc.

Typical Applications



Applications

- Active Filters
- Data Acquisition
- Portable Equipment
- Test Equipment
- Broadband Communication
- Process Control
- Audio and Video Processing

Ordering Information

Order Part Number	Top Marking		T_A	Package	
DIO2362HCN8	2362	Green or RoHS	-40 to 125°C	DFN2*2-8	Tape & Reel, 3000

Pin Assignments

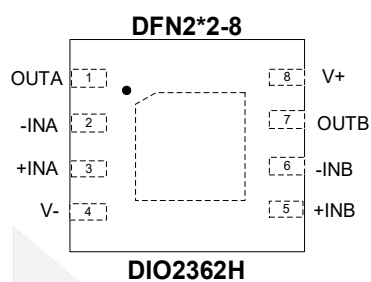


Figure 1 Top View

Pin Description

Pin name	Description
V+	Positive supply
V-	Negative supply
+INX	Positive Input
-INX	Negative Input
OUTX	Output

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter		Rating	Unit
Supply Voltage ($V+$ – $V-$)		7	V
Input Voltage		($V-$)-0.3V to ($V+$) 0.3V	V
Difference Input Voltage		$ V+ - V- $	V
Storage Temperature Range		-65 to 150	°C
Junction Temperature		150	°C
Lead Temperature Range		260	°C
ESD	HBM, JEDEC: JESD22-A114	8	kV

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter		Rating	Unit
Supply Voltage		1.8 to 5.5	V
Input Voltage		0 to 5	V
Operating Temperature Range		-40 to 125	°C

Electrical Characteristics

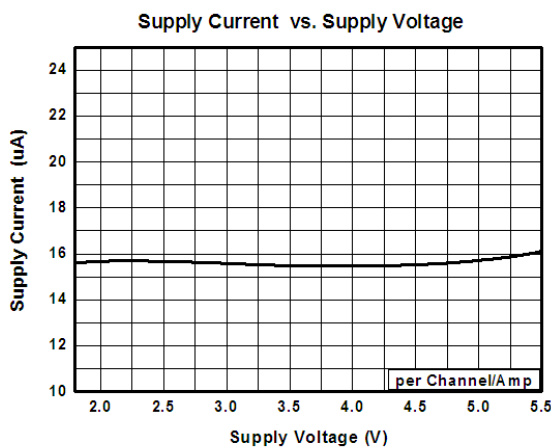
Typical value: $V_{CC}=5V$, $R_L=1M\Omega$ to $V_{CC}/2$, $V_{CM}=1/2V_{CC}$, $T_A = 25^\circ C$, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{OS}	Input Offset Voltage	V+=1.8V to 5.5V	-35		35	μV
I _B	Input Bias Current	V+=1.8V to 5.5V		1		pA
I _{OS}	Input Offset Current	V+=1.8V to 5.5V		1		pA
V _{CM}	Common Mode Voltage Range		0.7		(V+) +0.1	V
CMRR	Common Mode Rejection Ratio	-40°C≤T _A ≤125°C,		130		dB
A _{OL}	Open Loop Voltage Gain	R _L =50kΩ, V _O = 0.1 to (V+)-0.1	80	110		dB
ΔV _{OS} /ΔT	Input Offset Voltage Drift	-40°C≤T _A ≤125°C		0.05		μV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	R _L =50kΩ, -40°C≤T _A ≤125°C		4.992		V
V _{OL}	Output Voltage Low	R _L =50kΩ, -40°C≤T _A ≤125°C		8		mV
I _{SC}	Output Short Circuit Current	Source I _{SC} , V+=5V		34		mA
		Sink I _{SC} , V+=5V		34		
POWER SUPPLY						
PSRR	Power Supply Rejection Ration		100			dB
I _S	Supply Current per Channel/Amp	-40°C≤T _A ≤125°C		17	27	μA
DYNAMIC PERFORMANCE						
GBP	Gain Bandwidth Product	C _L =100pF, R _L =1MΩ		300		kHz
SR	Slew Rate	G=1, 2V Output Step		160		V/ms
t _s	Setting Time	G=1, 2V Output Step		1		ms
Om	Phase Margin			62		Deg
tr	Overload Recovery Time			40		μs
NOISE PERFORMANCE						
THD	Total Harmonic Distortion	f=1kHz, 4V _{PP} , R _L =5kΩ,		0.33		%
e _n	Voltage Noise Density	f=1kHz		70		nV/√Hz

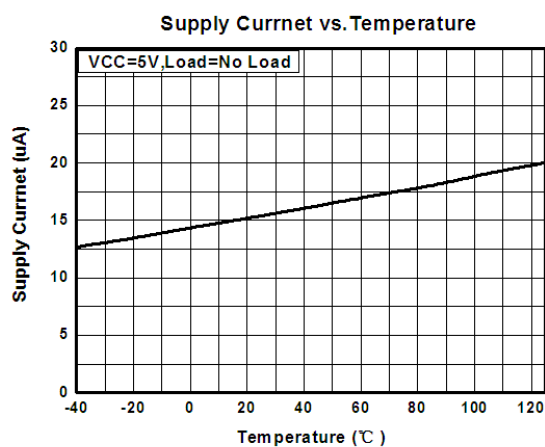
Specifications subject to change without notice.

Typical Performance Characteristics

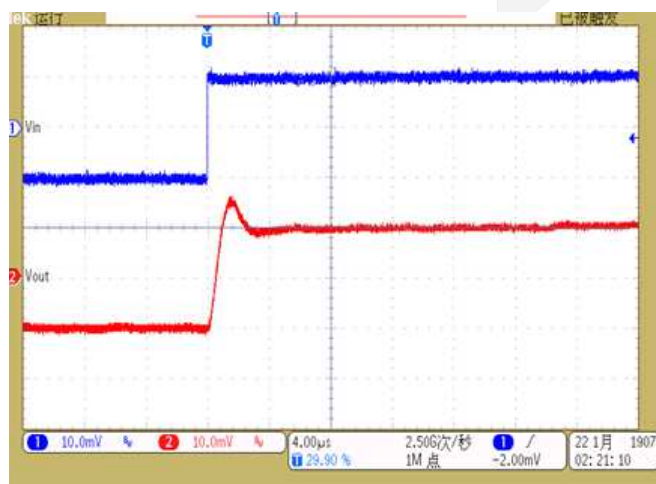
I_s vs. V_{CC}



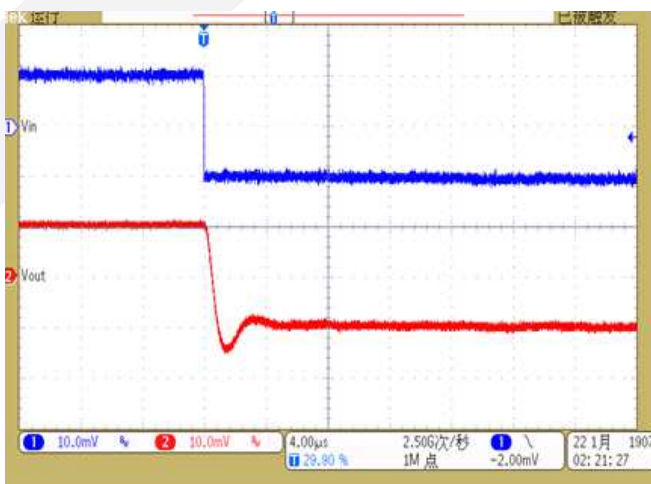
I_s vs. Temperature



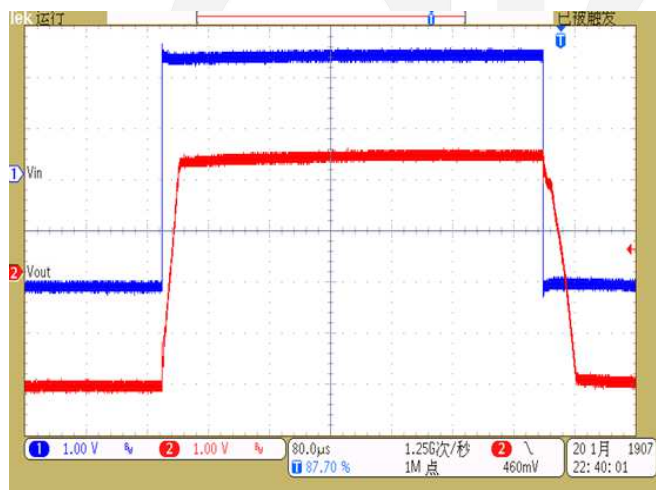
Small-signal Response
($V_{CC}=5V$, $C_L=200pF$)



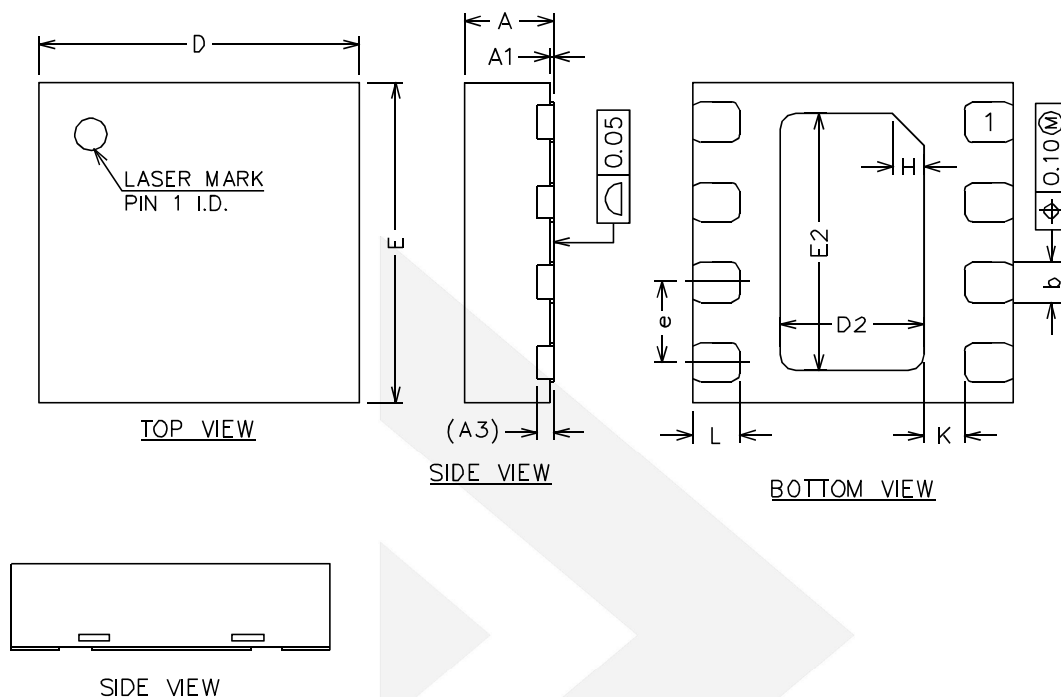
Small-signal Response
($V_{CC}=5V$, $C_L=200pF$)



Large-signal Response
($V_{CC}=5V$, $R_L=5.1k\Omega$)



Physical Dimensions: DFN2*2-8



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	0.50	0.55	0.65
A1	0.00	0.02	0.05
A3	0.10REF		
b	0.20	0.25	0.30
D	1.90	2.00	2.10
E	1.90	2.00	2.10
D2	0.80	0.90	1.00
E2	1.50	1.60	1.70
e	0.40	0.50	0.60
H	0.20REF		
K	0.15	0.25	0.35
L	0.25	0.30	0.35

CONTACT US

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For additional product information, or full datasheet, please contact with our Sales Department or Representatives.

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